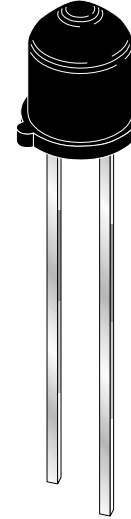
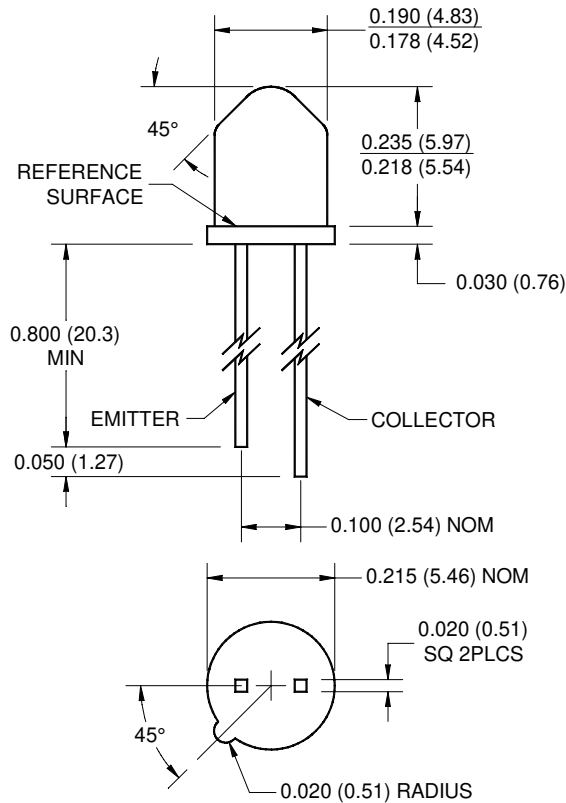
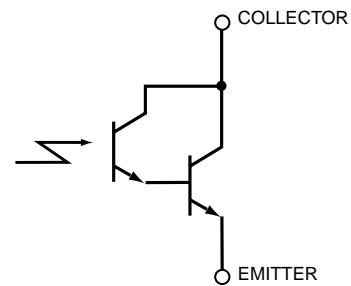


PACKAGE DIMENSIONS



SCHEMATIC



NOTES:

1. Dimensions for all drawings are in inches (mm).
2. Tolerance of $\pm .010$ (.25) on all non-nominal dimensions unless otherwise specified.
3. Orange stripe on the flange.

DESCRIPTION

The QSD733 is a silicon photodarlington encapsulated in an infrared transparent, black TO-18 package.

FEATURES

- NPN Silicon Photodarlington
- Package Type: Plastic TO-18
- Matched Emitter: QED523
- Narrow Reception Angle, 40°
- Daylight Filter
- Package material and color: black epoxy
- High Sensitivity

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Rating	Unit
Operating Temperature	T_{OPR}	-40 to +100	$^\circ\text{C}$
Storage Temperature	T_{STG}	-40 to +100	$^\circ\text{C}$
Soldering Temperature (Iron) ^(2,3,4)	T_{SOL-I}	240 for 5 sec	$^\circ\text{C}$
Soldering Temperature (Flow) ^(2,3)	T_{SOL-F}	260 for 10 sec	$^\circ\text{C}$
Collector-Emitter Voltage	V_{CE}	30	V
Emitter-Collector Voltage	V_{EC}	5	V
Power Dissipation ⁽¹⁾	P_D	100	mW

1. Derate power dissipation linearly 1.33 mW/ $^\circ\text{C}$ above 25 $^\circ\text{C}$.
2. RMA flux is recommended.
3. Methanol or isopropyl alcohols are recommended as cleaning agents.
4. Soldering iron 1/16" (1.6mm) minimum from housing.
5. $\lambda = 880$ nm, AlGaAs.

ELECTRICAL / OPTICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
Peak Sensitivity Wavelength		λ_{PS}	—	880	—	nm
Reception Angle		θ	—	± 20	—	Deg.
Collector-Emitter Dark Current	$V_{CE} = 10$ V, $E_e = 0$	I_{CEO}	—	—	100	nA
Collector-Emitter Breakdown	$I_C = 1$ mA	BV_{CEO}	30	—	—	V
Emitter-Collector Breakdown	$I_E = 100$ μA	BV_{ECO}	5	—	—	V
On-State Collector Current ⁽⁵⁾	$E_e = 0.125$ mW/cm ² , $V_{CE} = 5$ V	$I_{C(ON)}$	5.0	—	—	mA
Saturation Voltage ⁽⁵⁾	$E_e = 0.125$ mW/cm ² , $I_C = 2.0$ mA	$V_{CE(sat)}$	—	—	1.0	V
Rise Time	$V_{CC} = 5$ V, $R_L = 100$ Ω , $I_C = 0.15$ mA	t_r	—	20	—	μs
Fall Time		t_f	—	50	—	

Figure 1. Light Current vs. Radiant Intensity

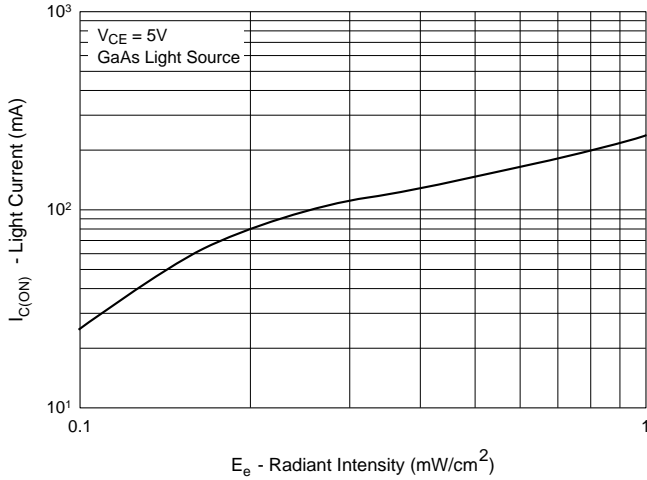


Figure 2. Angular Response Curve

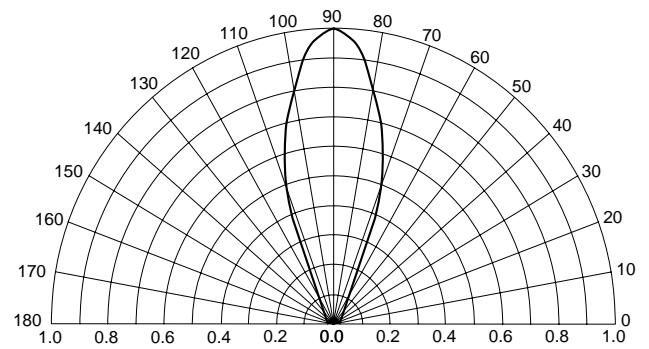


Figure 3. Dark Current vs. Collector - Emitter Voltage

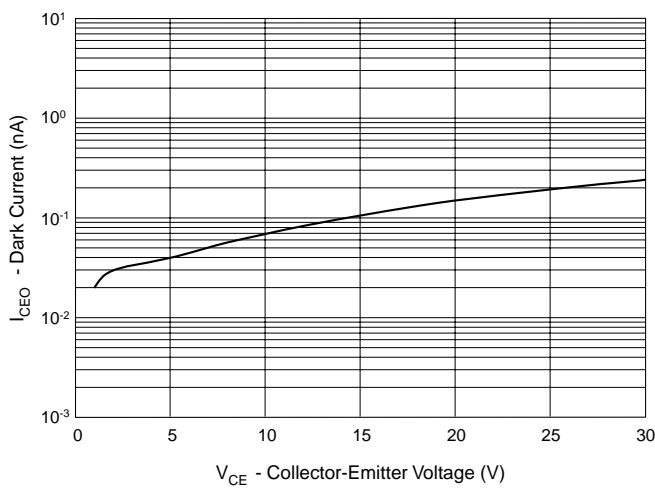


Figure 4. Light Current vs. Collector - Emitter Voltage

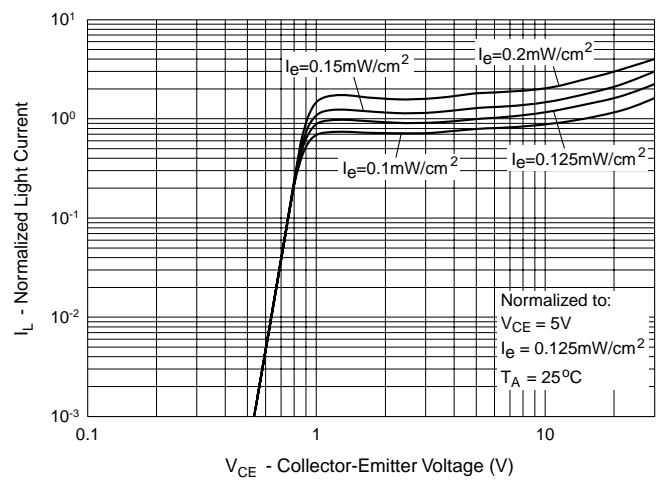
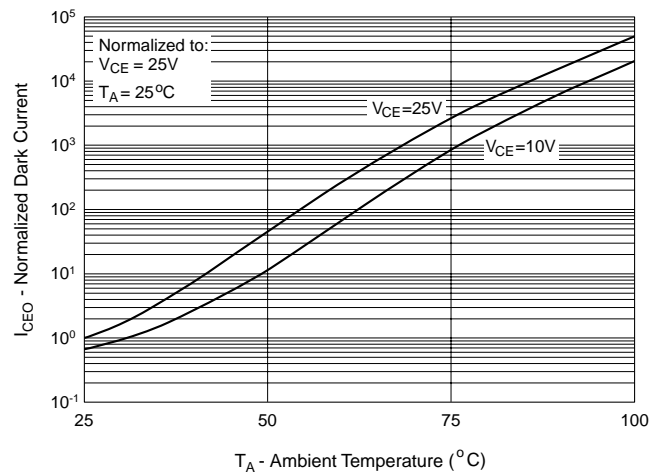


Figure 5. Dark Current vs. Ambient Temperature



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QSD733
Plastic Silicon Infrared Photodarlington

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General description

The QSD733 is a silicon photodarlington encapsulated in an infrared transparent, black TO-18 package.

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Features

- NPN silicon phototransistor
- Package type: Plastic TP-18
- Matched emitter: QED523
- Narrow reception angle, 40°
- Daylight filter
- Package material and color: black epoxy
- High sensitivity

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Product status/pricing/packaging

Product	Product status	Pricing*	Inventory check & ordering	Package type	Packing method
QSD733	Full Production	\$0.16	Purchase	TO-18	BULK
QSD733C	Full Production	N/A	Purchase	TO-18	BULK

* Fairchild 1,000 piece Budgetary Pricing

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